

Features

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery

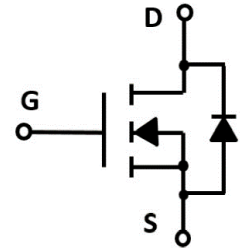
V_{DS}	$R_{DS(ON)}$ TYP	I_D
150V	130mΩ@10V	15A
	145mΩ@4.5V	

Application

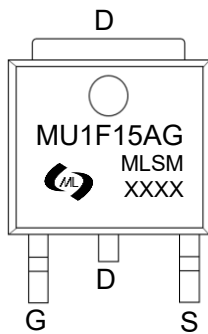
- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor



TO-252 view



Schematic diagram



Marking and pin assignment

MU1F15AG: Device code
 XXXX : Code



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	150	V
V_{GS}	Gate-Source Voltage	±20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$ 15	A

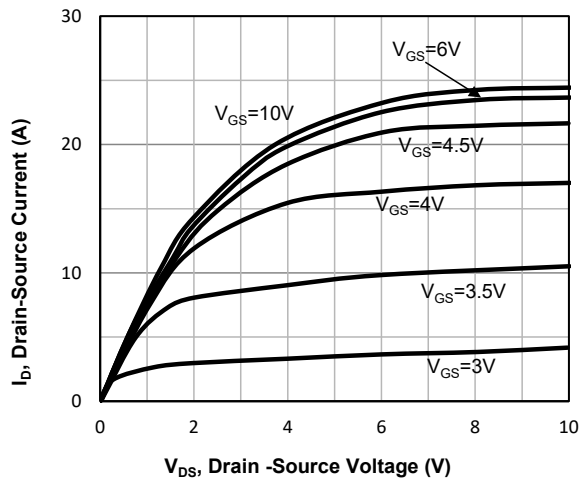
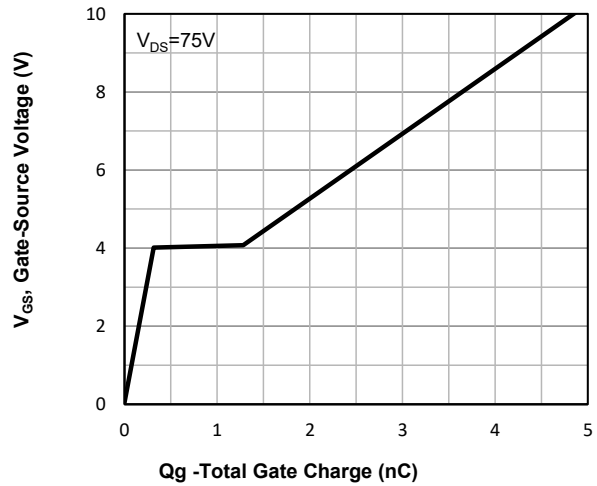
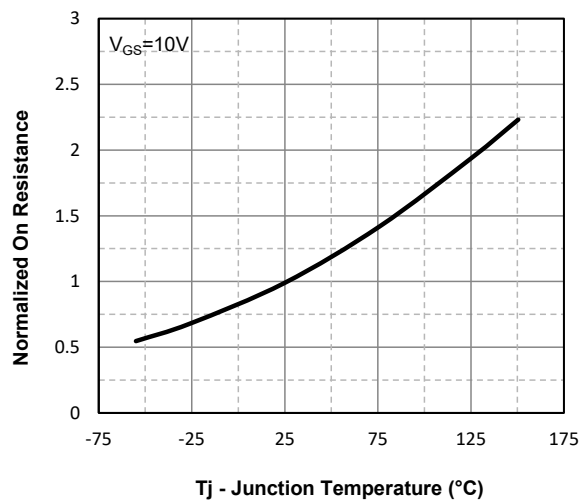
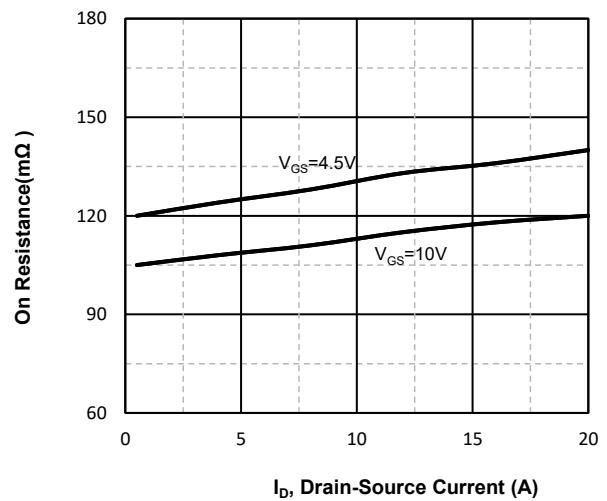
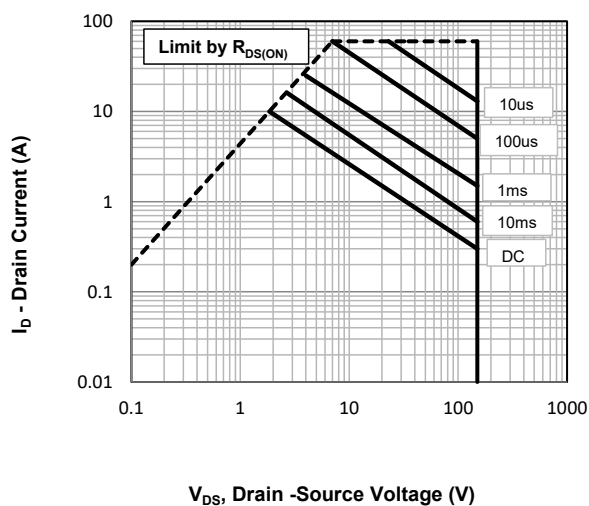
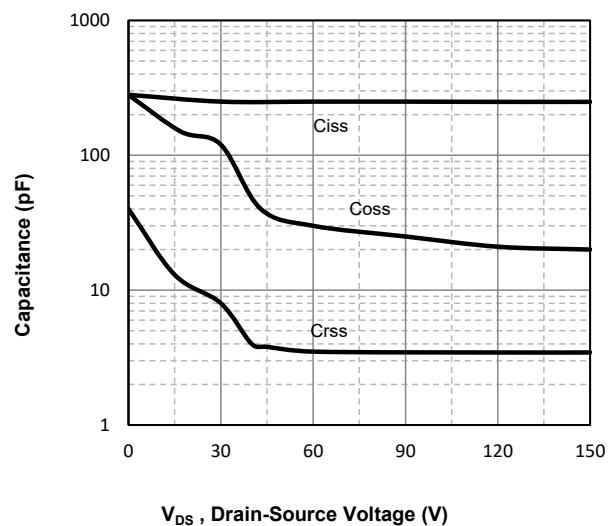
Mounted on Large Heat Sink

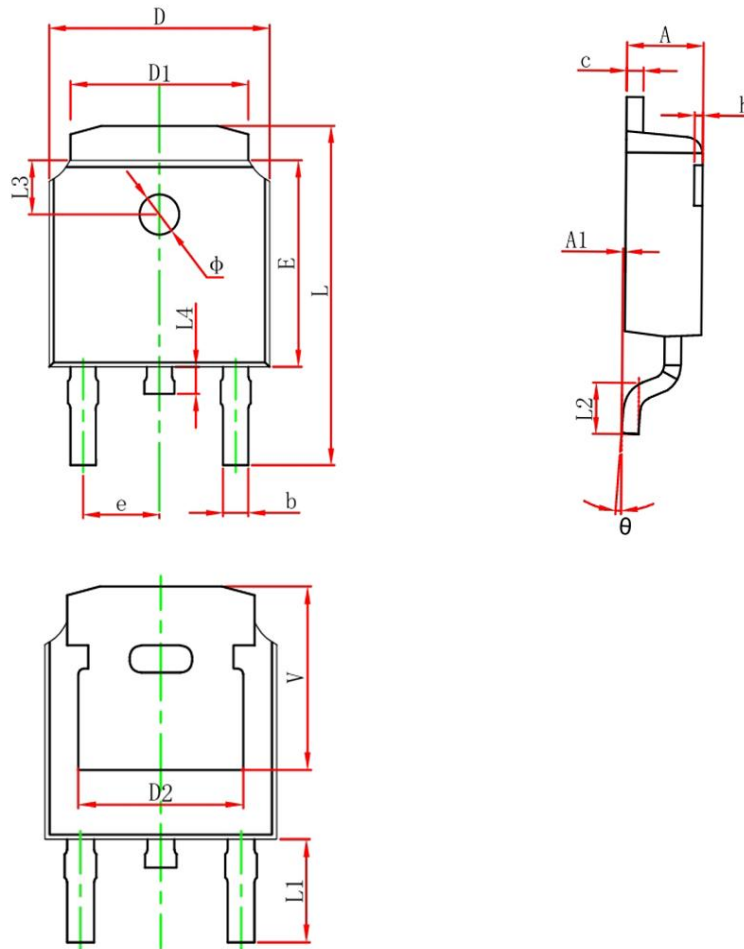
I_{DM}	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$ 60	A
I_D	Continuous Drain Current	$T_c=25^\circ\text{C}$ 15	A
P_D	Maximum Power Dissipation	$T_c=25^\circ\text{C}$ 41.6	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	50	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MU1F15AG	TO-252	MU1F15AG	2,500	5,000	35,000	13"reel

Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	150	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =150V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.5	--	3	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =20A	--	130	170	mΩ
		V _{GS} =4.5V, I _D =10A	--	145	200	mΩ
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =75V, V _{GS} =0V, f=1MHz	--	245	--	pF
C _{OSS}	Output Capacitance		--	27	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	3.6	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DS} =75V, I _D =10A, V _{GS} =10V	--	4.9	--	nC
Q _{gs}	Gate Source Charge		--	0.3	--	nC
Q _{gd}	Gate Drain Charge		--	0.9	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =75V, I _D =10A, V _{GS} =10V, R _G =6Ω	--	3.1	--	nS
t _r	Turn-on Rise Time		--	2.7	--	nS
t _{d(off)}	Turn-Off Delay Time		--	7.9	--	nS
t _f	Turn-Off Fall Time		--	2	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =10A	--	--	1.2	V

Typical Operating Characteristics

Fig1. Typical Output Characteristics

Fig2. Typical Gate Charge Vs. Gate-Source Voltage

Fig3. Normalized On-Resistance Vs. Temperature

Fig4. On-Resistance Vs. Drain-Source Current

Fig5. Maximum Safe Operating Area

Fig6 Typical Capacitance Vs. Drain-Source Voltage

TO-252 Package information


Symbol	Dimensions in Millimeters(mm)		Dimensions in Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.450	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.386	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
phi	1.100	1.300	0.043	0.051
theta	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	